

JAN2N4150

JAN2N4150 Information



For Reference Only

Part Number	JAN2N4150
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
Description	TRANS NPN 70V 10A TO-5
Package	TO-205AA, TO-5-3 Metal Can
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



JAN2N4150 Specifications

Manufacturer Part Number	JAN2N4150
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-205AA, TO-5-3 Metal Can
Series	Military, MIL-PRF-19500/394
Transistor Type	NPN
Current - Collector (Ic) (Max)	10A
Voltage - Collector Emitter Breakdown (Max)	70V
Vce Saturation (Max) @ Ib, Ic	2.5V @ 1A, 10A
Current - Collector Cutoff (Max)	10µA
DC Current Gain (hFE) (Min) @ Ic, Vce	40 @ 5A, 5V
Power - Max	1W
Frequency - Transition	-
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-205AA, TO-5-3 Metal Can
Supplier Device Package	TO-5
	Report errors?

JAN2N4150 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about JAN2N4150, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com